## NSN 5961-01-028-6204

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View Online at https://aerobasegroup.com/nsn/5961-01-028-6204 **Inclosure Material:** Metal **Overall Length:** 3.625 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 1.218 inches and 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakover voltage, dc **Current Rating Per Characteristic:** 2000.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0